

PAE1521P1

1-Line Ultra Low Capacitance Bi-d irectional TVS Diode

General Description

The PAE1521P1 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The PAE1521P1 has an ultra-low capacitance with a typical value at 0.3pF, and complies with the IEC 61000-4-2 (ESD) standard with ±20kV air and ±15kV contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm lead-free DFN package. The small size, ultra- low capacitance and high ESD surge protection make PAE1521P1 an ideal choice to protect cell phone and high-power USB.

Feature

- Ultra small package: 1.0 x0.6 x0.5mm
- Ultra low capacitance: 0.3pF typical
- Ultra low leakag : nA level
- Operating voltage : 15V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - -IEC 61000-4-2 (ESD) immunity test
 - Air discharge : ±20kV
 - Contact discharge : ±15kV
 - IEC61000-4-5 (Lightning) 2.5A(8/20µs)
- RoHS Compliant

Application

- Cellular Handsets and Accessories
- Serial ATA
- MDDI Ports
- USB Ports
- PCI Express and Serial SATA Ports

Mechanical Characteristics

- Package: DFN1006-2 (1.0x0.6 x0.5mm)
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020

DFN-1006







Maximum Ratings (TA=25°C Unless otherwise specified)

| Parameter | Symbol | Value | Unit |
|---------------------------------|--------|-------------|------|
| Peak Pulse Power(8/20µs) | Ppk | 90 | W |
| Peak Pulse Current(8/20µs) | IPP | 2.5 | А |
| ESD per IEC 61000-4-2 (Air) | VECD | ±20 | kV |
| ESD per IEC 61000-4-2 (Contact) | VESD | ±15 | |
| Operating Temperature Range | TJ | −55 to +150 | °C |
| Storage Temperature Range | Tstg | −55 to +150 | °C |

Electrical Characteristics (TA=25°C Unless otherwise specified)

| Parameter | Symbol | Min | Тур | Max | Unit | Test Condition |
|-------------------------|----------------|------|-----|-----|------|-----------------------------|
| Reverse Working Voltage | Vrwm | | | 15 | V | |
| Breakdown Voltage | Vbr | 16.7 | | | V | IT = 1mA |
| Reverse Leakage Current | I _R | | | 0.2 | μA | VRWM = 15V |
| Clamping Voltage | Vc | | | 26 | V | IPP = 1A (8 x 20µs pulse) |
| Clamping Voltage | Vc | | | 35 | V | IPP = 2.5A (8 x 20µs pulse) |
| Junction Capacitance | CJ | | 0.3 | 0.5 | pF | VR = 0V, f = 1MHz |



Typical Characteristics



Junction Capacitance vs. Reverse Voltage



Clamping Voltage vs. Peak Pulse Current



8 X 20µs Pulse Waveform





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Package Information (DFN1006)

D



| | DIMENSIONS | | | | | |
|------|-------------|-------|-------|-----------|----------|-------|
| OVM | MILLIMETERS | | | INCHES | | |
| 5111 | MIN | NOM | MAX | MIN | NOM | MAX |
| А | 0.450 | 0.500 | 0.550 | 0.018 | 0.020 | 0.022 |
| A1 | 0.000 | 0.020 | 0.050 | 0.000 | 0.001 | 0.002 |
| b | 0.450 | 0.50 | 0.550 | 0.018 | 0.020 | 0.022 |
| С | 0.120 | 0.150 | 0.180 | 0.005 | 0.006 | 0.007 |
| D | 0.950 | 1.000 | 1.050 | 0.037 | 0.039 | 0.041 |
| е | 0.65 BSC | | | 0.026 BSC | | |
| Е | 0.55 | 0.60 | 0.65 | 0.022 | 0.024 | 0.026 |
| L | 0.20 | 0.25 | 0.30 | 0.008 | 0.010 | 0.012 |
| L1 | 0.05REF | | | (| 0.002REF | = |
| h | 0.07 | 0.12 | 0.17 | 0.003 | 0.005 | 0.007 |

Suggested Land Pattern



| SYM | DIMENSIONS | | | | |
|-----|-------------|--------|--|--|--|
| | MILLIMETERS | INCHES | | | |
| Х | 0.60 | 0.024 | | | |
| Y1 | 0.50 | 0.020 | | | |
| Y2 | 0.30 | 0.012 | | | |
| Y3 | 0.80 | 0.032 | | | |
| Z | 1.30 | 0.052 | | | |

> Ordering Information

| Part Number | Description | Quantity |
|-------------|--------------|-----------|
| PAE1521P1 | DFN1006 Reel | 10000 pcs |



Recommand IR Reflow Soldering Thermal Profile



| Profile Feature | Pb-Free Assembly Profile |
|-------------------------------------------------|--------------------------|
| Temperature Min. (Tsmin) | 150°C |
| Temperature Max. (Tsmax) | 200°C |
| Time (ts) from (Tsmin to Tsmax) | 60-120 seconds |
| Average Ramp-up Rate (tL to tP) | 3°C/second max. |
| Liquidous Temperature (TL) | 217°C |
| Time (tL) Maintained Above (TL) | 60 – 150 seconds |
| Peak Temperature | 260°C +0°C / -5°C |
| Time (tP) within 5°C of actual Peak Temperature | 30 seconds |
| Ramp-down Rate (TP to TL) | 6°C/second max |
| Time 25°C to Peak Temperature | 8 minutes max. |



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